

Product Features

- PI74ALVTC16601 is designed for low voltage operation, $V_{DD} = 1.65V$ to $3.6V$
- Supports Live Insertion
- 3.6V I/O Tolerant Inputs and Outputs
- Bus Hold
- High Drive, $-32/64mA$ @ $3.3V$
- Uses patented noise reduction circuitry
- Power-off high impedance inputs and outputs
- Industrial operation at $-40^{\circ}C$ to $+85^{\circ}C$
- Packages available:
 - 56-pin 240-mil wide plastic TSSOP (A56)
 - 56-pin 173-mil wide plastic TVSOP (K56)

Product Description

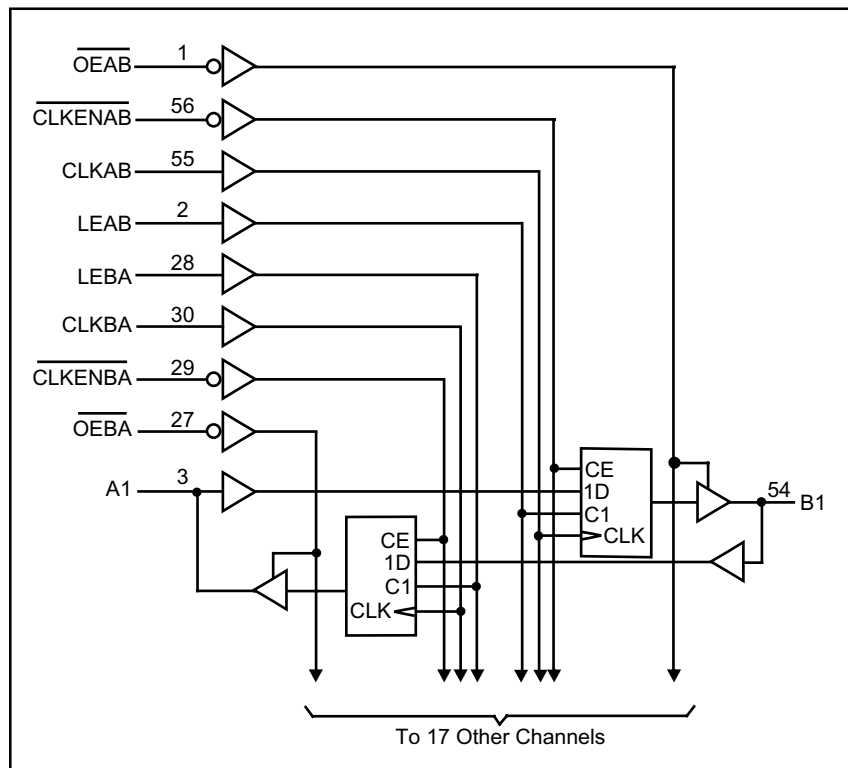
Pericom Semiconductor's PI74ALVTC series of logic circuits are produced using the Company's advanced 0.35 micron CMOS technology, achieving industry leading speed.

The PI74ALVTC16601 uses D-type latches and D-type flip-flops with 3-state outputs to allow data flow in transparent, latched, and clocked modes.

Data flow in each direction is controlled by Output Enable ($\overline{OEAB}$ and $\overline{OEBA}$), Latched Enable ($\overline{LEAB}$ and $\overline{LEBA}$), and Clock ($\overline{CLKAB}$ and $\overline{CLKBA}$) inputs. The clock can be controlled by the Clock Enable ($\overline{CLKENAB}$ and $\overline{CLKENBA}$) inputs. For A-to-B data flow, the device operates in the transparent mode when $\overline{LEAB}$ is HIGH. When $\overline{LEAB}$ is LOW, the A data is latched if $\overline{CLKAB}$ is held at a high or low logic level. If $\overline{LEAB}$ is low, the A-bus is stored in the latch/flip-flop on the low-to-high transition of $\overline{CLKAB}$. When $\overline{OEAB}$ is low, the outputs are active. When $\overline{OEAB}$ is HIGH, the outputs are in the high-impedance state.

Data flow for B to A is similar to that of A to B but uses $\overline{OEBA}$, $\overline{LEBA}$, $\overline{CLKBA}$, and $\overline{CLKENBA}$.

Logic Block Diagram



To ensure the high-impedance state during power up or power down, $\overline{OE}$ should be tied to V_{DD} through a pull-up resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The PI74ALVTC16601 offers both I/O Tolerant, which allows it to operate in mixed 1.65/3.6V systems, and "Bus Hold" which retains the data input's last state preventing "floating" inputs and eliminating the need for pullup/down resistors.

Pin Description

Pin Name	Description
$\overline{OE}$	Output Enable Input (Active LOW)
CLK	Clock Input (Active HIGH)
Dx	Data Inputs
Qx	3-State Outputs
GND	Ground
VDD	Power

Truth Table^{(1)†}

Inputs					Output B
$\overline{CLKENAB}$	$\overline{OEAB}$	LEAB	CLKAB	A	
X	H	X	X	X	Z
X	L	H	X	L	L
X	L	H	X	H	H
H	L	L	X	X	B ₀ ‡
H	L	L	X	X	B ₀ ‡
L	L	L	↑	L	L
L	L	L	↑	H	H
L	L	L	L OR H	X	B ₀ ‡

Pin Configuration

OEAB	1	56	CLKENAB
LEAB	2	55	CLKAB
A1	3	54	B1
GND	4	53	GND
A2	5	52	B2
A3	6	51	B3
VDD	7	50	VDD
A4	8	49	B4
A5	9	48	B5
A6	10	47	B6
GND	11	46	GND
A7	12	45	B7
A8	13	44	B8
A9	14	43	B9
A10	15	42	B10
A11	16	41	B11
A12	17	40	B12
GND	18	39	GND
A13	19	38	B13
A14	20	37	B14
A15	21	36	B15
VDD	22	35	VDD
A16	23	34	B16
A17	24	33	B17
GND	25	32	GND
A18	26	31	B18
OEBA	27	30	CLKBA
LEBA	28	29	CLKENBA

Notes:

- H = High Signal Level
L = Low Signal Level
Z = High Impedance
↑ = LOW-to-HIGH Transition

† A-to-B data flow is shown: B-to-A flow is similar but uses $\overline{OEBA}$, LEBA, CLKBA, and CLKENBA.

‡ Output level before the indicated steady-state input conditions were established.

Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Supply Voltage Range, V_{DD}	-0.5V to 4.6V
Input Voltage Range, V_I	-0.5V to 4.6V
Output Voltage Range, V_O (3-States)	-0.5V to 4.6V
Output Voltage Range, $V_O^{(1)}$ (Active)	-0.5V to $V_{DD}+0.5V$
DC Input Diode Current (I_{IK}) $V_I < 0V$	-50mA
DC Output Diode Current (I_{OK})	
$V_O < 0V$	-50mA
$V_O > V_{DD}$	$\pm 50mA$
DC Output Source/Sink Current (I_{OH}/I_{OL})	-64/128mA
DC V_{DD} or GND Current per Supply Pin (I_{CC} or GND)	$\pm 100mA$
Storage Temperature Range, T_{stg}	-65°C to 150°C

Note:

Stresses greater than those listed under MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

Recommended Operating Conditions⁽²⁾

			Min.	Max.	Units
V_{DD}	Supply voltage	Operating	1.65	3.6	V
		Data Retention Only	1.2	3.6	
V_{IH}	High-level input voltage	$V_{DD} = 2.7V$ to 3.6V	2.0		
V_{IL}	Low-level input voltage	$V_{DD} = 2.7V$ to 3.6V		0.8	
V_I	Input voltage		-0.3	3.6	
V_O	Output voltage	Active State	0	V_{DD}	mA
		Off State	0	3.6	
	Output current in I_{OH}/I_{OL}	$V_{DD} = 3.0V$ to 3.6V		-32/64	
		$V_{DD} = 3.0V$ to 3.6V		± 24	
		$V_{DD} = 2.3V$ to 2.7V		± 18	
		$V_{DD} = 1.65V$ to 1.95V		± 6	
$\Delta t/\Delta v$	Input transistion rise or fall rate ⁽³⁾		0	10	ns/V
T_A	Operating free-air temperature		-40	85	C

Notes:

1. Absolute maximum of I_O must be observed.
2. Unused control inputs must be held HIGH or LOW to prevent them from floating.
- 3 As measured between 0.8V and 2.0V, $V_{DD}=3.0V$.

Electrical Characteristics over Recommended Operating Free-Air Temperature Range

(unless otherwise noted)

DC Characteristics ($2.7V < V_{DD} \leq 3.6V$)

	Parameter	Conditions	V_{DD}	Min.	Typ.	Max.	Units
V_{IK}	Input Clamp Diode	$I_{IK} = -18mA$	3.0			-1.2	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\mu A$	2.7 - 3.6	$V_{DD} - 0.2$			
		$I_{OH} = -12mA$	2.7	2.2			
		$I_{OH} = -18mA$	3.0	2.4			
		$I_{OH} = -24mA$		2.2			
		$I_{OH} = -32mA$		2.0			
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\mu A$	2.7 - 3.6			0.2	
		$I_{OL} = 12mA$	2.7			0.4	
		$I_{OL} = 18mA$	3.0			0.4	
		$I_{OL} = 24mA$				0.45	
		$I_{OL} = 32mA$				0.5	
		$I_{OL} = 64mA$				0.75	
I_I	Input Leakage Current	$V_I = V_{DD}$, or GND	3.6			± 5.0	μA
I_{OZ}	3-State Output Leakage	$V_O = 3.6V$	2.7			± 10	
I_{OFF}	Power-OFF Leakage Current	V_I or $V_O \leq 3.6V$	0			10	
I_{HOLD}	Bus Hold Current A or B Outputs	$V_I = 0.8V$	3.0	75			
		$V_I = 2.0V$		-75			
		$V_I = 0$ to 3.6V	3.6			± 500	
I_{DD}	Quiescent Supply Current	$V_I = V_{DD}$ or GND	2.7 - 3.6			50	
		$V_{DD} \leq (V_I, V_O) \leq 3.6V$				± 50	
ΔI_{DD}	Increase in I_{DD} per input	$V_{IH} = V_{DD} - 0.6V$, Other inputs at V_{DD} or Gnd				400	

Electrical Characteristics over Recommended Operating Free-Air Temperature Range (unless otherwise noted)
(continued from previous page)

DC Characteristics ($2.3V \leq V_{DD} \leq 2.7V$)

Description	Parameters	Conditions	V_{DD}	Min.	Typ.	Max.	Units
V_{IK}	Input Clamp Diode	$I_{IK} = -18mA$	2.3			-1.2	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\mu A$	2.3 - 2.7	$V_{DD} - 0.2$			
		$I_{OH} = -12mA$	2.3	1.8			
		$I_{OH} = -18mA$		1.7			
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\mu A$	2.3 - 2.7			0.2	
		$I_{OL} = 12mA$	2.3			0.4	
		$I_{OL} = 18mA$				0.5	
		$I_{OL} = 24mA$				0.55	
I_I	Input Leakage Current	$V_I = V_{DD}$ or GND	2.7			± 5.0	μA
I_{OZ}	3-State Output Leakage	$V_O = 3.6V$	2.3			± 10	
I_{OFF}	Power-OFF Leakage Current	V_I or $V_O \leq 3.6V$	0			10	
$I_{HOLD}^{(1)}$	Bus Hold Current A or B Outputs	$V_I = 0.7V$	2.5		90		μA
		$V_I = 1.7V$			-90		
I_{DD}	Quiescent Supply Current	$V_I = V_{DD}$ or GND	2.3 - 2.7			40	
		$V_{DD} \leq (V_I, V_O) \leq 3.6V$				± 40	
ΔI_{DD}	Increase in I_{DD} per input	$V_{IH} = V_{DD} - 0.6V$, Inputs at V_{DD} or Gnd				400	

Note:

1. Not Guaranteed

Electrical Characteristics over Recommended Operating Free-Air Temperature Range (unless otherwise noted)
(continued from previous page)

DC Characteristics ($1.65V \leq V_{DD} \leq 1.95V$)

Description	Parameters	Conditions	V_{DD}	Min.	Typ.	Max.	Units
V_{IK}	Input Clamp Diode	$I_{IK} = -18mA$	1.65			-1.2	V
V_{OH}	HIGH Level Output Voltage	$I_{OH} = -100\mu A$	1.65-1.95	$V_{DD} - 0.2$			
		$I_{OH} = -6mA$	1.65	1.4			
V_{OL}	LOW Level Output Voltage	$I_{OL} = 100\mu A$				0.2	
		$I_{OL} = 6mA$				0.3	
I_I	Input Leakage Current	$V_I = V_{DD}$ or GND	1.95			± 5.0	μA
I_{OZ}	3-State Output Leakage	$V_O = 3.6V$	1.65			± 10	
I_{OFF}	Power-OFF Leakage Current	$V_I = V_O \leq 3.6V$	0			10	
$I_{HOLD}^{(1)}$	Bus Hold Current A or B Outputs	$V_I = 0.4$	1.65		50		
		$V_I = 1.3$			-50		
I_{DD}	Quiescent Supply Current	$V_I = V_{DD}$ or GND	1.65-1.95			20	
		$V_{DD} \leq (V_I, V_O) \leq 3.6V$				± 20	
ΔI_{DD}	Increase in I_{DD} per input	$V_I = V_{DD} - 0.6V$, Other inputs at V_{DD} or Gnd				400	

Note:

1. Not Guaranteed

Timing Requirements over recommended operating free-air temperature range

(unless otherwise noted, see Figures 1 thru 4)

			$V_{DD} = 1.8V$ $\pm 0.15V$		$V_{DD} = 2.5V$ $\pm 0.2V$		$V_{DD} = 3.3V$ $\pm 0.3V$		Units
			Min	Max	Min	Max	Min	Max	
f_{clock} Clock Frequency				150		180		180	MHz
t_w Pulse duration	LE high		2.0		1.5		1.5		ns
	CLK high or low		3.5		3.0		2.0		
t_{su} Setup time	Data before CLK $\uparrow$		2.5		2.1		1.9		
	Data before LE $\downarrow$	CLK high	1.9		1.6		1.4		
		CLK low	1.3		1.1		0.9		
	$\overline{CLKEN}$ before CLK $\uparrow$		2.0		1.7		1.5		
t_h Hold time	Data after CLK $\uparrow$		1.0		0.8		0.6		
	Data after LE $\downarrow$	CLK high	1.7		1.4		1.2		
		CLK low	1.9		1.7		1.5		
	$\overline{CLKEN}$ after CLK $\uparrow$		1.0		0.6		0.4		

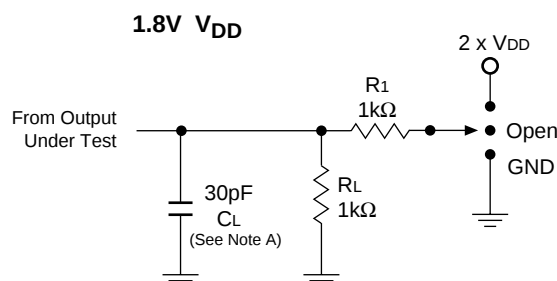
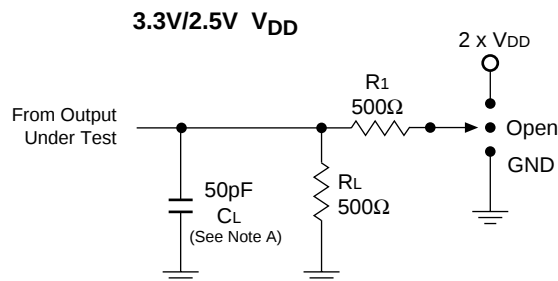
Switching Characteristics over recommended operating free-air temperature range

(unless otherwise noted, see Figures 1 thru 4)

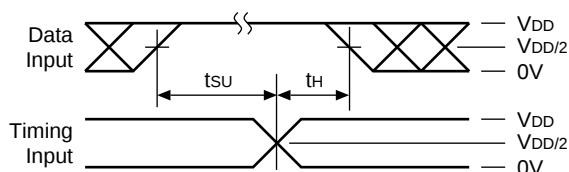
Parameter	From (Input)	To (Output)	$V_{DD} = 1.8V$ $\pm 0.15V$		$V_{DD} = 2.5V$ $\pm 0.2V$		$V_{DD} = 3.3V$ $\pm 0.3V$		Units
			Min	Max	Min	Max	Min	Max	
f_{max}			150		180		180		MHz
t_{pd}	A or B	B or A	1.2	4.5	1	4.1	1	3.4	ns
	LEAB or LEBA	A or B	1.3	4.9	1	4.7	1	3.9	
	$\overline{CLKAB}$ or $\overline{CLKBA}$		1.5	5.3	1.2	5.0	1.2	4.0	
t_{en}	$\overline{OEAB}$ or $\overline{OEBA}$		1.2	4.7	1	3.7	1	3.7	
t_{dis}			1.6	5.6	1	3.5	1	3.5	

Test Circuits and Switching Waveforms

Parameter Measurement Information ($V_{DD} = 1.65V - 3.6V$)



Setup, Hold, and Release Timing



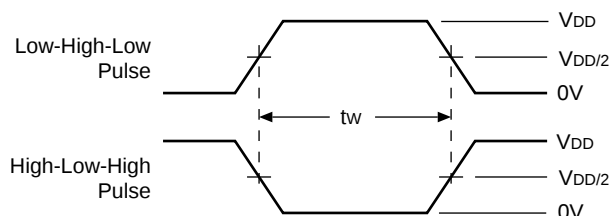
Notes:

- C_L includes probe and jig capacitance.
- Waveform 1 is for an output with internal conditions such that the output is LOW except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is HIGH except when disabled by the output control.
- All input pulses are supplied by generators having the following characteristics: $PRR \leq 10 \text{ MHz}$, $Z_O = 50\Omega$, $t_r \leq 2\text{ns}$, $t_f \leq 2\text{ns}$, **measured from 10% to 90%, unless otherwise specified.**
- The outputs are measured one at a time with one transition per measurement.

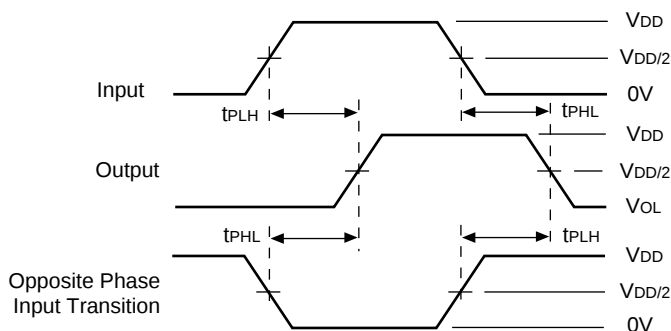
Switch Position

Test	S1
t_{PD}	Open
t_{PLZ}/t_{PZL}	$2 \times V_{DD}$
t_{PHZ}/t_{PZH}	GND

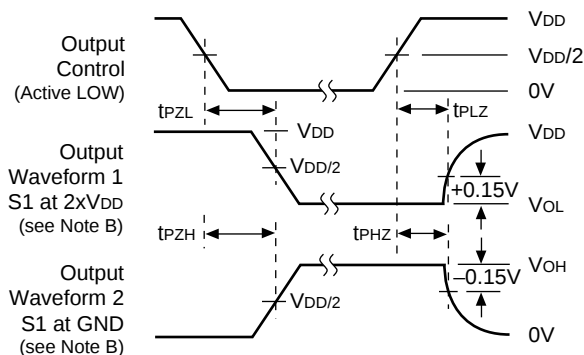
Pulse Width



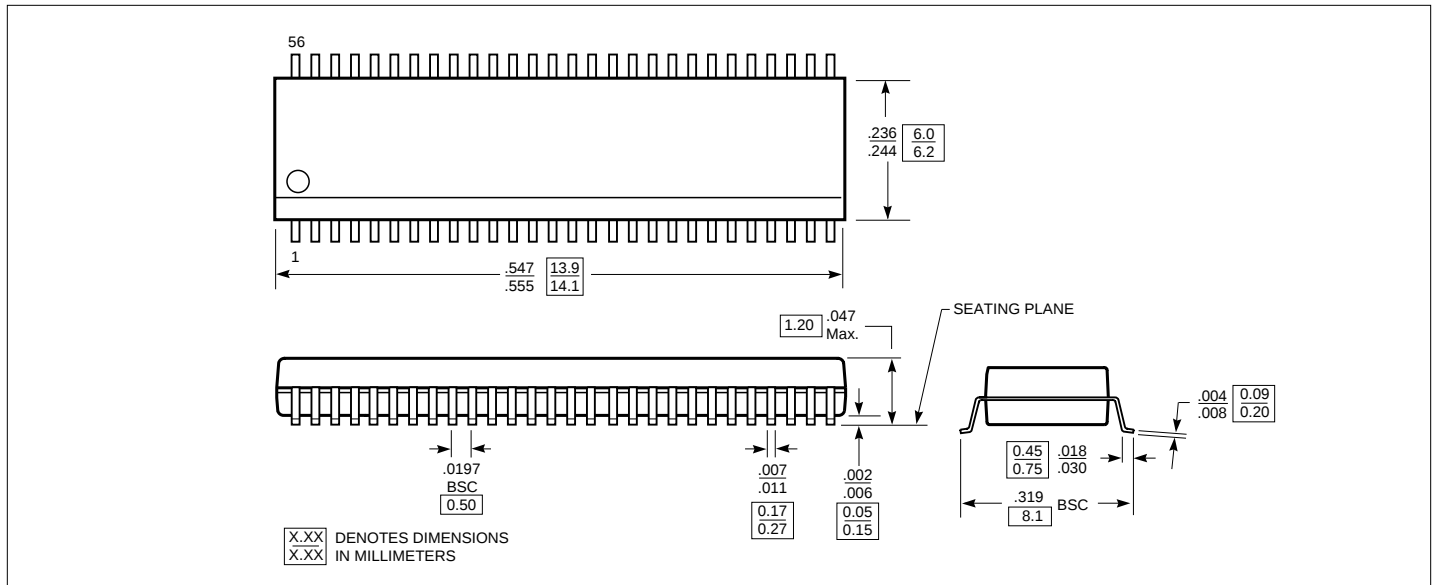
Propagation Delay



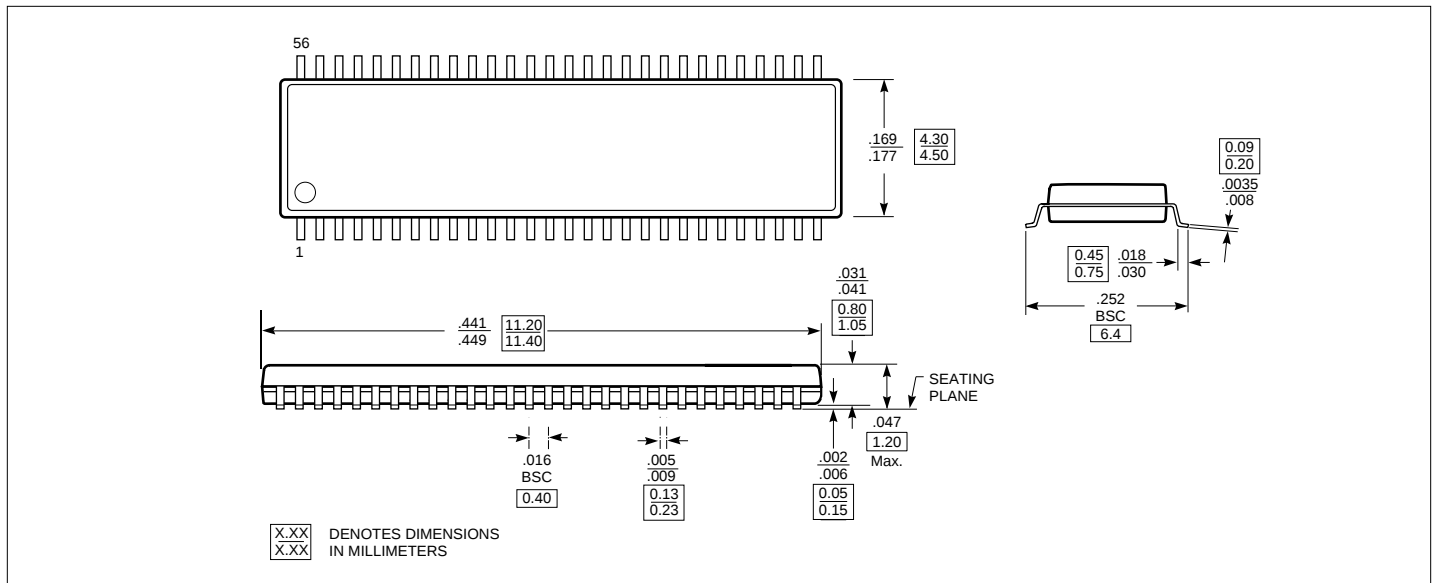
Enable Disable Timing



Packaging Mechanical: 56-pin TSSOP (A)



Packaging Mechanical: 56-pin TVSOP (K)



Ordering Information	Package - Pins
PI74ALVTC16601A	TSSOP - 56
PI74ALVTC16601K	TVSOP - 56